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APPLICANTS

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ST ** CONTINUING DATA ***** none

** FOREIGN APPLICATIONS ***** *ST*
 REPUBLIC OF KOREA 2002-53086 09/04/2002

IF REQUIRED, FOREIGN FILING LICENSE GRANTED
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Foreign Priority claimed 35 USC 119 (a-d) conditions met Verified and Acknowledged	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance <i>Handwritten signature</i> Examiner's Signature Initials	STATE OR COUNTRY KOREA, REPUBLIC OF	SHEETS DRAWING 9	TOTAL CLAIMS 25	INDEPENDENT CLAIMS 2
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ADDRESS
 09629
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TITLE
 Method of fabricating top gate type thin film transistor having low temperature polysilicon

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